

BZT55 Series

List

List.....	1
Package outline.....	2
Features.....	2
Mechanical data.....	2
Maximum ratings	2
Electrical characteristics.....	3~4
Rating and characteristic curves.....	5
Pinning information.....	6
Suggested solder pad layout.....	6
Packing information.....	7
Reel packing.....	8
Suggested thermal profiles for soldering processes.....	8
High reliability test capabilities.....	9

BZT55 Series

500mW Surface Mount Zener Diodes - 2.4V-51V

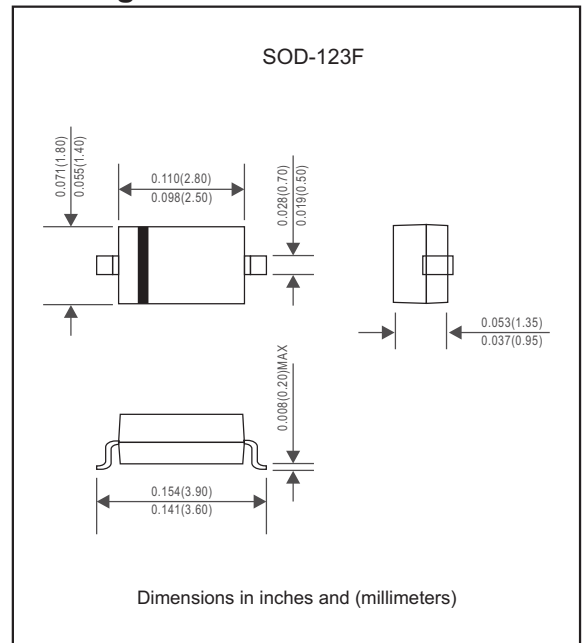
Features

- Silicon epitaxial planar chip structure.
- Zener breakdown voltage range, 2.4V to 51V ex.BZT55C2V4
- Zener breakdown voltage range, 2.2V to 36V ex.BZT55B2V2
- Small package size for high density applications.
- Ideally suited for automated assembly processes.
- Pb-Free package is available.
- Suffix "-H" indicates Halogen-free parts, ex.BZT55C2V4-H.

Mechanical data

- Epoxy : UL94-V0 rated flame retardant
- Case : Molded plastic, SOD-123F
- Terminals :Plated terminals, solderable per MIL-STD-750, Method 2026
- Polarity : Indicated by cathode band
- Mounting Position : Any
- Weight : Approximated 0.010 gram

Package outline



Maximum ratings (at $T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Forward voltage	@IF = 10mA	V_F			0.9	V
Total power dissipation	at $T_A=25^{\circ}\text{C}$ Mounted on FR-5 board, note1	P_D			500	mW
Thermal resistance	Junction to ambient, note1 Junction to case, note1	$R_{\theta JA}$ $R_{\theta JC}$		305 200		$^{\circ}\text{C/W}$ $^{\circ}\text{C/W}$
Operating junction temperature range		T_J	-55		+150	$^{\circ}\text{C}$
Storage temperature range		T_{STG}	-55		+150	$^{\circ}\text{C}$

Note1. Device mounted on ceramic PCB; 7.6mm x 9.4mm x 0.87mm with pad area 25mm²

BZT55 Series

Electrical characteristics (at $T_A=25^{\circ}\text{C}$ unless otherwise noted)

Part No.	Marking code	Zener voltage			Test current	Zener impedance			Leakage current		Typical Temperature Typical Coefficient	
		V _Z @ I _{ZT}				I _{ZT}	Z _{ZT} @ I _{ZT}	Z _{ZK} @ I _{ZK}	I _{ZK}	I _R	V _R	@ I _{ZT} (mV/°C)
		Min.(V)	Nom.(V)	Max.(V)		mA	(Ω)Max	(Ω)Max	mA	(uA)Max	Volts	
BZT55C2V4	WX	2.2	2.4	2.6	5	100	600	1.0	50.0	1.0	-3.5	0
BZT55C2V7	W1	2.5	2.7	2.9	5	100	600	1.0	20.0	1.0	-3.5	0
BZT55C3V0	W2	2.8	3.0	3.2	5	95	600	1.0	10.0	1.0	-3.5	0
BZT55C3V3	W3	3.1	3.3	3.5	5	95	600	1.0	5.0	1.0	-3.5	0
BZT55C3V6	W4	3.4	3.6	3.8	5	90	600	1.0	5.0	1.0	-3.5	0
BZT55C3V9	W5	3.7	3.9	4.1	5	90	600	1.0	3.0	1.0	-3.5	0
BZT55C4V3	W6	4.0	4.3	4.6	5	90	600	1.0	3.0	1.0	-3.5	0
BZT55C4V7	W7	4.4	4.7	5.0	5	80	500	1.0	3.0	2.0	-3.5	0.2
BZT55C5V1	W8	4.8	5.1	5.4	5	60	480	1.0	2.0	2.0	-2.7	1.2
BZT55C5V6	W9	5.2	5.6	6.0	5	40	400	1.0	1.0	2.0	-2.0	2.5
BZT55C6V2	WA	5.8	6.2	6.6	5	10	150	1.0	3.0	4.0	0.4	3.7
BZT55C6V8	WB	6.4	6.8	7.2	5	15	80	1.0	2.0	4.0	1.2	4.5
BZT55C7V5	WC	7.0	7.5	7.9	5	15	80	1.0	1.0	5.0	2.5	5.3
BZT55C8V2	WD	7.7	8.2	8.7	5	15	80	1.0	0.7	5.0	3.2	6.2
BZT55C9V1	WE	8.5	9.1	9.6	5	15	100	1.0	0.5	6.0	3.8	7.0
BZT55C10	WF	9.4	10	10.6	5	20	150	1.0	0.2	7.0	4.5	8.0
BZT55C11	WG	10.4	11	11.6	5	20	150	1.0	0.1	8.0	5.4	9.0
BZT55C12	WH	11.4	12	12.7	5	25	150	1.0	0.1	8.0	6.0	10.0
BZT55C13	WI	12.4	13	14.1	5	30	170	1.0	0.1	8.0	7.0	11.0
BZT55C15	WJ	13.8	15	15.8	5	30	200	1.0	0.1	10.5	9.2	13.0
BZT55C16	WK	15.3	16	17.1	5	40	200	1.0	0.1	11.2	10.4	14.0
BZT55C18	WL	16.8	18	19.1	5	45	225	1.0	0.1	12.6	12.4	16.0
BZT55C20	WM	18.8	20	21.2	5	55	225	1.0	0.1	14.0	14.4	18.0
BZT55C22	WN	20.8	22	23.3	5	55	250	1.0	0.1	15.4	16.4	20.0
BZT55C24	WO	22.8	24	25.6	5	70	250	1.0	0.1	16.8	18.4	22.0
BZT55C27	WP	25.1	27	28.9	2	80	300	0.5	0.1	18.9	21.4	25.3
BZT55C30	WQ	28.0	30	32.0	2	80	300	0.5	0.1	21.0	24.4	29.4
BZT55C33	WR	31.0	33	35.0	2	80	325	0.5	0.1	23.1	27.4	33.4
BZT55C36	WS	34.0	36	38.0	2	90	350	0.5	0.1	25.2	30.4	37.4
BZT55C39	WT	37.0	39	41.0	2	130	350	0.5	0.1	27.3	33.4	41.2
BZT55C43	WU	40.0	43	46.0	2	100	700	1.0	0.1	32.0	10.0	12.0
BZT55C47	WV	44.0	47	50.0	2	100	750	1.0	0.1	35.0	10.0	12.0
BZT55C51	WW	48.0	51	54.0	2	100	750	1.0	0.1	38.0	10.0	12.0

Note:

1. Tested with pulses, period = 5ms, pulse width = 300 μs .
2. When provided, otherwise, parts are provided with date code only, and type number identifications appears on reel only.
3. f=1KHz.

BZT55 Series

Electrical characteristics (at $T_A=25^{\circ}\text{C}$ unless otherwise noted)

Part No.	Marking code	Zener voltage		Test current	Zener impedance			Leakage current	
		V _z @ I _{zT}		I _{zT}	Z _{zT} @ I _{zT}	Z _{zK} @ I _{zK}	I _{zK}	I _R	V _R
		Min.(V)	Max.(V)	mA	(Ω)Max	(Ω)Max	mA	(uA)Max	Volts
BZT55B2V2	12	2.22	2.41	5	100	1000	0.5	120.0	0.7
BZT55B2V4	22	2.43	2.63	5	100	1000	0.5	100.0	1.0
BZT55B2V7	32	2.69	2.91	5	110	1000	0.5	100.0	1.0
BZT55B3V0	42	3.01	3.22	5	120	1000	0.5	50.0	1.0
BZT55B3V3	52	3.32	3.53	5	120	1000	0.5	20.0	1.0
BZT55B3V6	62	3.60	3.845	5	100	1000	1.0	10.0	1.0
BZT55B3V9	72	3.89	4.16	5	100	1000	1.0	5.0	1.0
BZT55B4V3	82	4.17	4.43	5	100	1000	1.0	5.0	1.0
BZT55B4V7	92	4.55	4.75	5	100	800	0.5	2.0	1.0
BZT55B5V1	A2	4.98	5.20	5	80	500	0.5	2.0	1.5
BZT55B5V6	C2	5.49	5.73	5	60	200	0.5	1.0	2.5
BZT55B6V2	E2	6.06	6.33	5	60	100	0.5	1.0	3.0
BZT55B6V8	F2	6.65	6.93	5	40	60	0.5	0.5	3.5
BZT55B7V5	H2	7.28	7.6	5	30	60	0.5	0.5	4.0
BZT55B8V2	J2	8.02	8.36	5	30	60	0.5	0.5	5.0
BZT55B9V1	L2	8.85	9.23	5	30	60	0.5	0.5	6.0
BZT55B10	05	9.77	10.21	5	30	60	0.5	0.1	7.0
BZT55B11	15	10.76	11.22	5	30	60	0.5	0.1	8.0
BZT55B12	25	11.74	12.24	5	30	80	0.5	0.1	9.0
BZT55B13	35	12.91	13.49	5	37	80	0.5	0.1	10.0
BZT55B15	45	14.34	14.98	5	42	80	0.5	0.1	11.0
BZT55B16	55	15.85	16.51	5	50	80	0.5	0.1	12.0
BZT55B18	65	17.56	18.35	5	65	80	0.5	0.1	13.0
BZT55B20	75	19.52	20.39	5	85	100	0.5	0.1	15.0
BZT55B22	85	21.54	22.47	5	100	100	0.5	0.1	17.0
BZT55B24	95	23.72	24.78	5	120	120	0.5	0.1	19.0
BZT55B27	A5	26.19	27.53	5	150	150	0.5	0.1	21.0
BZT55B30	C5	29.19	30.69	5	200	200	0.5	0.1	23.0
BZT55B33	E5	32.15	33.79	5	250	250	0.5	0.1	25.0
BZT55B36	F5	35.07	36.87	5	300	300	0.5	0.1	27.0

Note:

1. Tested with pulses, period = 5ms, pulse width = 300us.
2. When provided, otherwise, parts are provided with date code only, and type number identifications appears on reel only.
3. $f=1\text{KHz}$.

Rating and characteristic curves (BZT55 Series)

FIG. 1-TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE

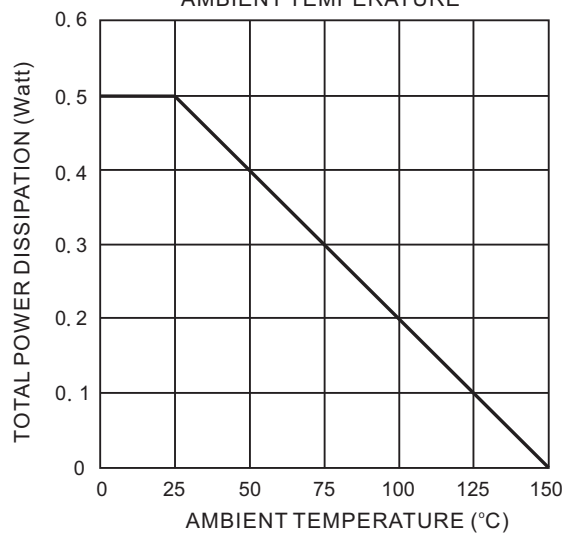
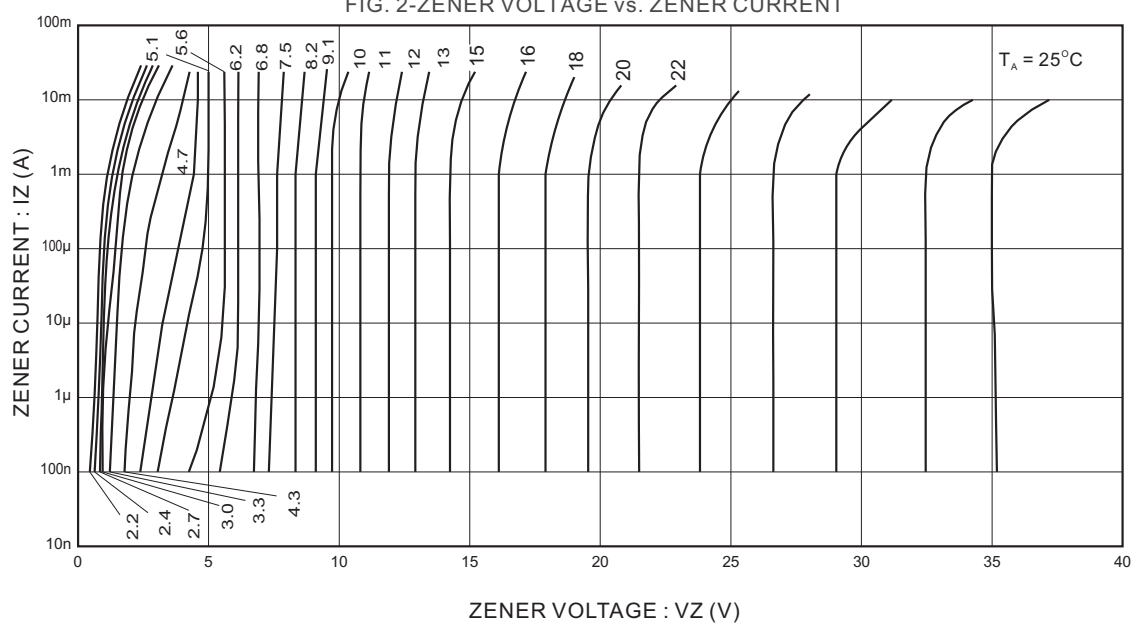


FIG. 2-ZENER VOLTAGE vs. ZENER CURRENT

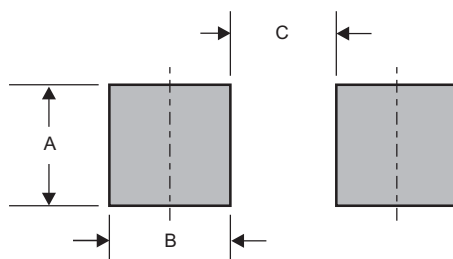


BZT55 Series

Pinning information

Pin	Simplified outline	Symbol
Pin1 cathode Pin2 anode		

Suggested solder pad layout

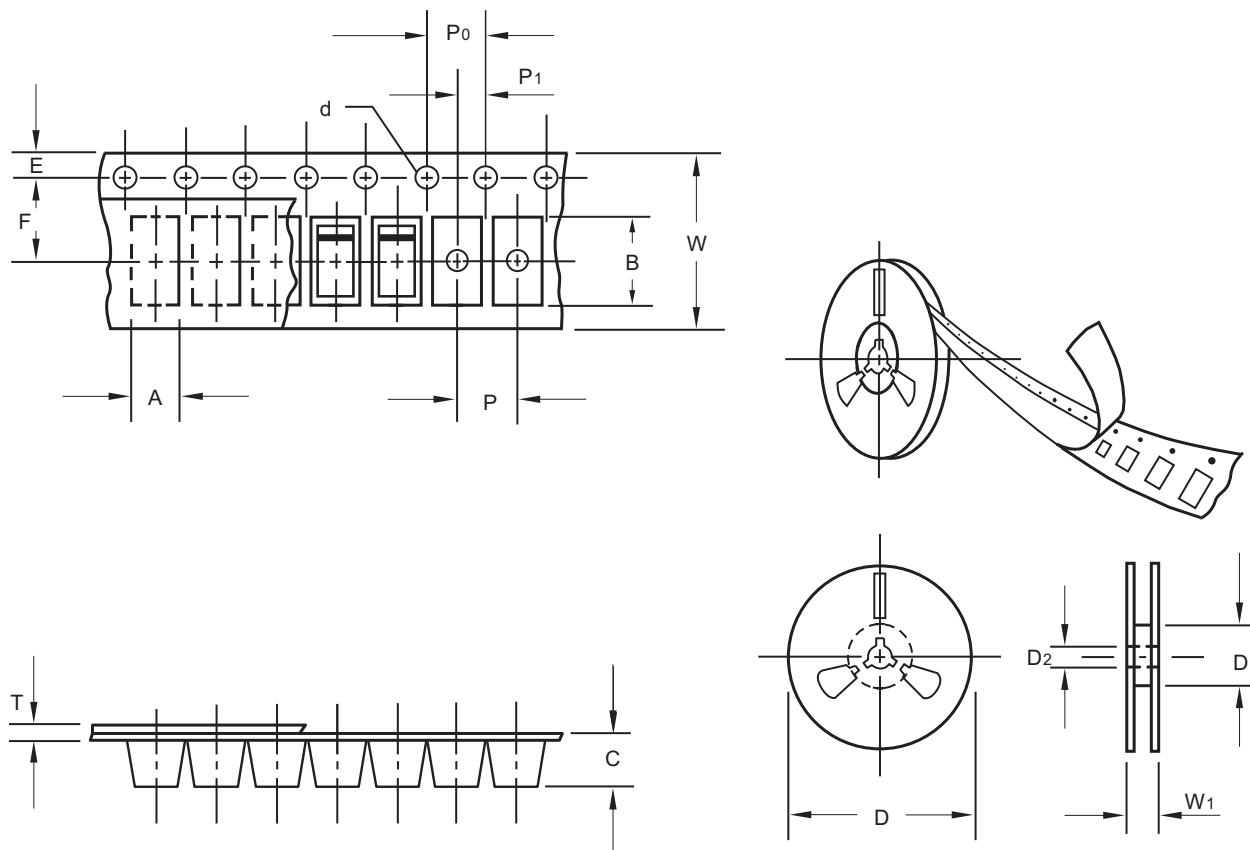


Dimensions in inches and (millimeters)

PACKAGE	A	B	C
SOD-123F	0.048 (1.22)	0.036 (0.91)	0.093 (2.36)

BZT55 Series

Packing information



unit:mm

Item	Symbol	Tolerance	SOD-123F
Carrier width	A	0.1	2.00
Carrier length	B	0.1	3.85
Carrier depth	C	0.1	1.10
Sprocket hole	d	0.1	1.50
13" Reel outside diameter	D	2.0	-
13" Reel inner diameter	D1	min	-
7" Reel outside diameter	D	2.0	178.00
7" Reel inner diameter	D1	min	62.00
Feed hole diameter	D2	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	3.50
Punch hole pitch	P	0.1	4.00
Sprocket hole pitch	P0	0.1	4.00
Embossment center	P1	0.1	2.00
Overall tape thickness	T	0.1	0.23
Tape width	W	0.3	8.00
Reel width	W1	1.0	11.40

Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

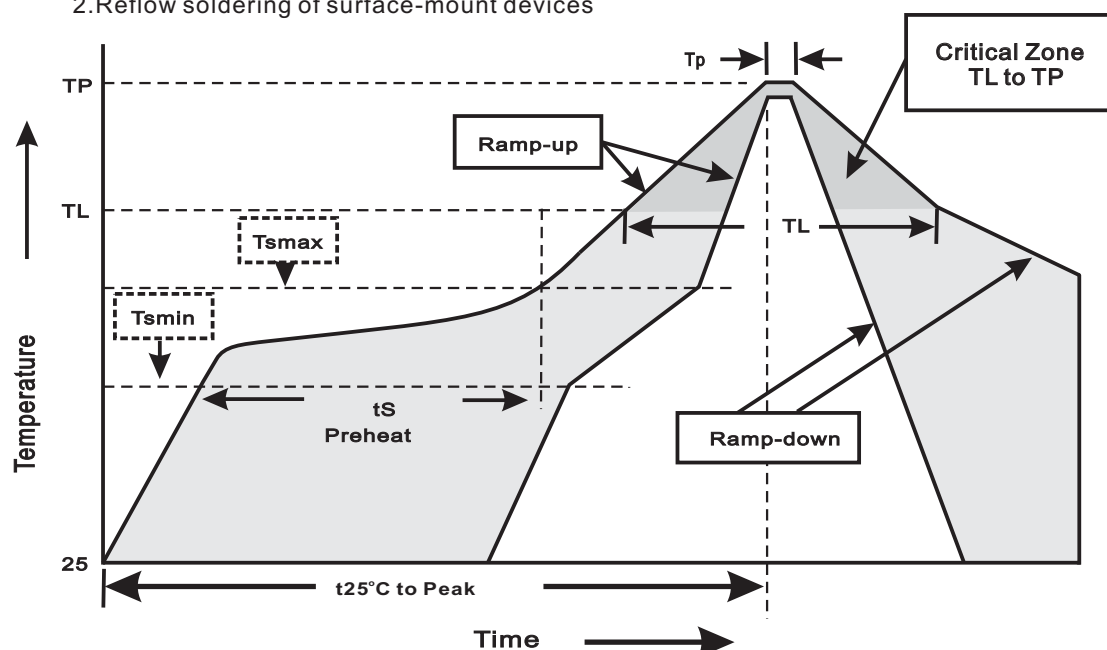
BZT55 Series

Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SOD-123F	7"	3,000	4.0	30,000	183*123*183	178	382*257*387	240,000	9.5

Suggested thermal profiles for soldering processes

- 1.Storage environment: Temperature=5°C~40°C Humidity=55%±25%
- 2.Reflow soldering of surface-mount devices



3.Reflow soldering

Profile Feature	Soldering Condition
Average ramp-up rate(T _L to T _P)	<3°C/sec
Preheat -Temperature Min(T _{smmin}) -Temperature Max(T _{smmax}) -Time(min to max)(t _s)	150°C 200°C 60~120sec
T _{smmax} to T _L -Ramp-upRate	<3°C/sec
Time maintained above: -Temperature(T _L) -Time(t _L)	217°C 60~260sec
Peak Temperature(T _P)	255°C-0/+5°C
Time within 5°C of actual Peak Temperature(t _P)	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes

BZT55 Series

High reliability test capabilities

Item Test	Conditions	Reference
1. Solder Resistance	at $260 \pm 5^{\circ}\text{C}$ for $10 \pm 2\text{sec.}$	MIL-STD-750D METHOD-2031
2. Solderability	at $245 \pm 5^{\circ}\text{C}$ for 5 sec.	MIL-STD-202F METHOD-208
3. High Temperature Reverse Bias	$V_z = V_z \text{ Nom} * 80\%$ at $T_j = 150^{\circ}\text{C}$ for 168 hrs.	MIL-STD-750D METHOD-1038
4. Pressure Cooker	$15P_{\text{SIG}}$ at $T_A = 121^{\circ}\text{C}$ for 4 hrs.	JESD22-A102
5. Temperature Cycling	-55°C to $+125^{\circ}\text{C}$ dwelled for 30 min. and transferred for 5min. total 10 cycles.	MIL-STD-750D METHOD-1051
6. Humidity	at $T_A = 85^{\circ}\text{C}$, RH=85% for 1000hrs.	MIL-STD-750D METHOD-1021
7. High Temperature Storage Life	at 175°C for 1000 hrs.	MIL-STD-750D METHOD-1031